

Bi-Directional Power Amplifier 825MHz-880MHz



Product Description

The RFBA825880M02 is a bi-directional power amplifier with a frequency range of 825 to 880MHz.

The power output of this amplifier is 35dBm typical. The typical small signal gain is 16dB with a gain flatness of \pm 1dB. This power amplifier works with a +12 VDC power supply.

The power amplifier's input/ output connectors are MCX-KE.

The operating temperature of this product is -10 to +55°C.

Features

- Receiver Gain: 16dB typical
- Receiver NF: <2.5dB
- Transmitter Gain : 34dB typical
- Transmitter P1dB : 35dBm
- ACPR : ≤-32dBc (@±5MHz Bandwidth)

Typical Applications

- Wireless Infrastructure Military and Aerospace
- Applications
- Test Instrumentation
- Radar Systems
- 5G Wireless Communications
- Microwave Radio Systems
- TR Modules
- Research and Development
- Cellular Base Stations

Parameter -		RX			ТΧ		
	Min	Тур	Max	Min	Тур	Max	Units
Frequency Range	825		835	870		880	MHz
Gain		16			36		dB
Gain Flatness		±1			±1		dB
Noise Figure		2.2					dB
Input Return Loss		-10			-20		dB
Output Power for 1dB Compression (P1dB)		15			35		dBm
TX Group delay					45		ns
ACPR(@±5MHz Bandwidth)					-35		dBc
Efficiency @ Output Power					10		%
Power Supply (+12V)		0.9			0.85	2.5	А
Weight			0.2	20			lbs
Input / Output Connectors	MCX-KE						
	Epoxy Sealed (Standard)						
Package Seal -	Hermetically Sealed (Optional)						

Note: The input current of the interface input level is less than 500uA and the output current of the output level is less than 1mA.

Electrical Specifications, T_A = +25°C Vcc +12V



RFBA825880M02

Absolute Maximum Ratings

Parameter	Rating
Supply Voltage Range	+12.5VDC
*RF Input Power (RFIN)	Psat – Large Signal Gain

Bias Up Procedure

1. Connect ground

2. Connect input and output with 50 Ohm source/load. (In band VSWR < 1.9:1 or >10dB return loss.)

3. Connect +12VDC and make sure power supply can handle max current.

Bias Down Procedure

- 1. Turn off +12VDC
- 2. Remove +12VDC Connection
- 3. Remove RF Connection
- 4. Remove ground

Environmental Specifications and Test Standards

Parameter	Description
Operational Temperature	-10ºC to +55ºC (Case Temperature)
Storage Temperature	-50°C to +105°C
Thermal Shock	-10ºC → +55ºC (5 Cycles / 10 hours)
**Random Vibration	MIL-STD-202G Table 214-I, Test Condition Letter C 1.5 Hours Per Axis
High Temperature Burn In	Temperature +85°C for 72 Hours
Shock	 Weight >20g, 50g half sine wave for 11ms, Speed variation 3.44m/s Weight <=20g, 100g Half sine wave for 6ms, Speed variation 3.75m/s Total 18 times (6 directions, 3 repetitions per direction).
Altitude	Standard: 30,000 Ft (Epoxy Sealed Controlled Environment) Optional: Hermetically Sealed (60,000 ft. 1.0 PSI min)
Hermetically Sealed (Optional)	MIL-STD-883 (For Hermetically Sealed Units)

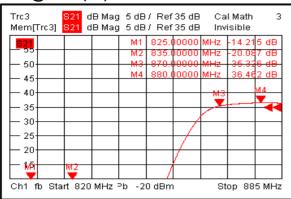
*Maximum RF input power is set to assure safety of amplifier. Input power may be increased at own risk to achieve full power of amplifier. Please reference gain and power curves.

**For vibration testing details please see additional information section.

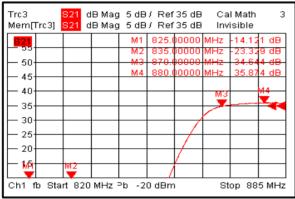
RF-LAMBDA THE LEADER OF RF BROADBAND SOLUTIONS

Typical Performance Plots

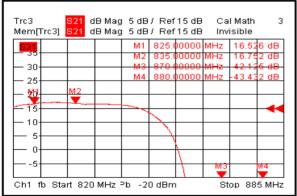
Gain@+25°C (TX)



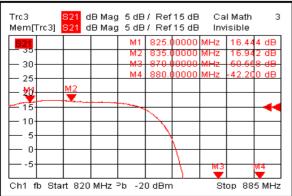
Gain@+55°C (TX)



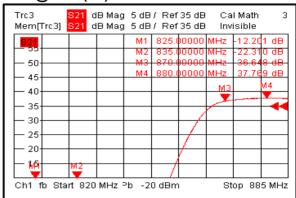
Gain@+25°C (RX)



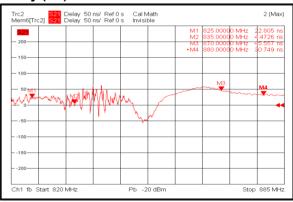
Gain@-10°C (RX)



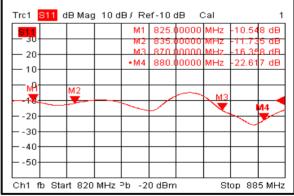
Gain@-10°C (TX)



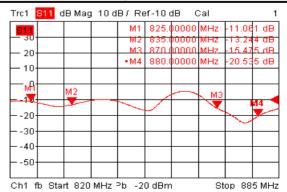
Delay (TX)



Input Return Loss @+25°C (RX)

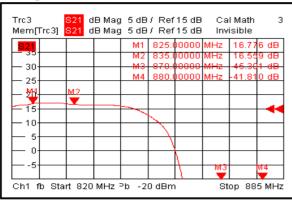


Input Return Loss @-10°C (RX)

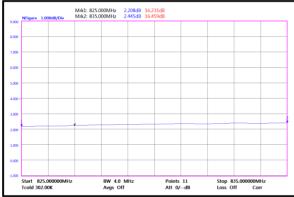




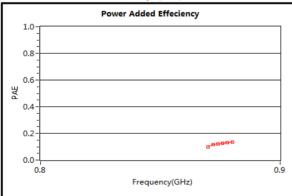
Gain@+55°C (RX)



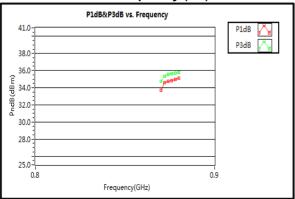
Noise Figure (RX)

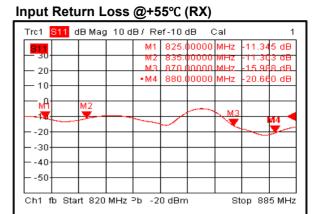


Power Added Efficiency (TX)

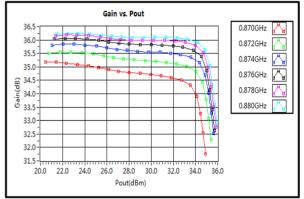


P1dB & P3dB vs. Frequency (TX)

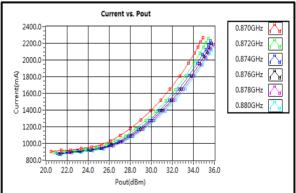




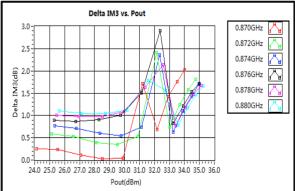
Gain vs. Output Power (TX)



Current vs. Pout (TX)

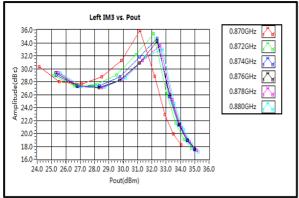


Delta IM3 vs. Pout (TX)

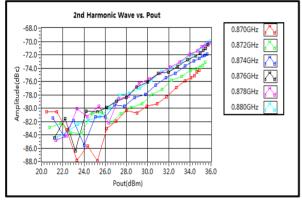




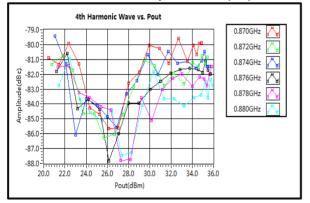
Left IM3 vs. Pout (TX)



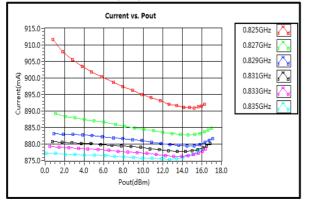
2nd Harmonic Wave Output Power (TX)



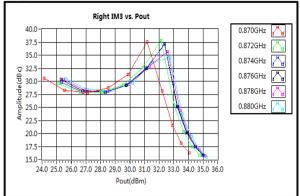
4th Harmonic Wave Output Power (TX)



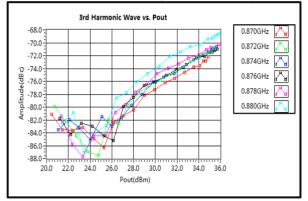
Current vs. Pout (RX)



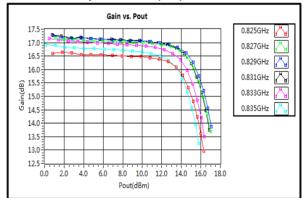
Right IM3 vs. Pout (TX)



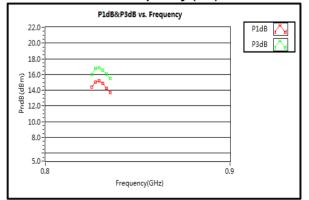
3rd Harmonic Wave Output Power (TX)



Gain vs. Output Power (RX)

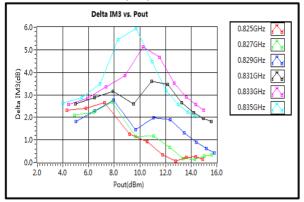


P1dB & P3dB vs. Frequency (RX)

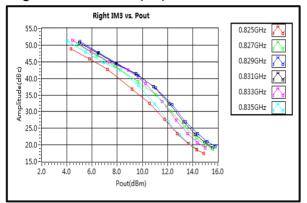




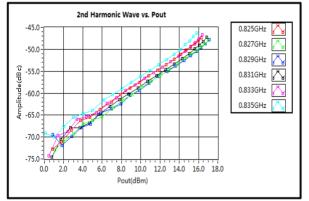
Delta IM3 vs. Pout (RX)



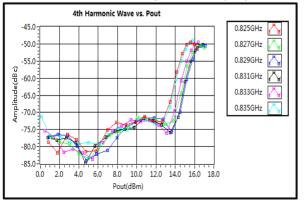
Right IM3 vs. Pout (RX)



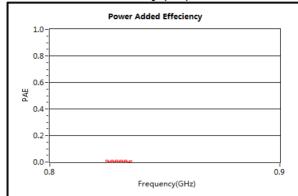
2nd Harmonic Wave Output Power (RX)



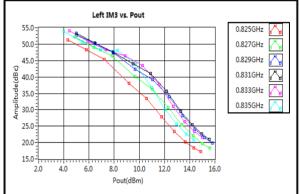
4th Harmonic Wave Output Power (RX)



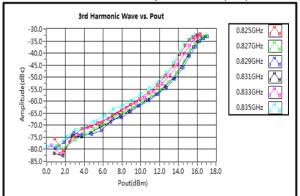
Power Added Efficiency (RX)



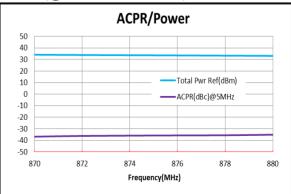
Left IM3 vs. Pout (RX)



3rd Harmonic Wave Output Power (RX)



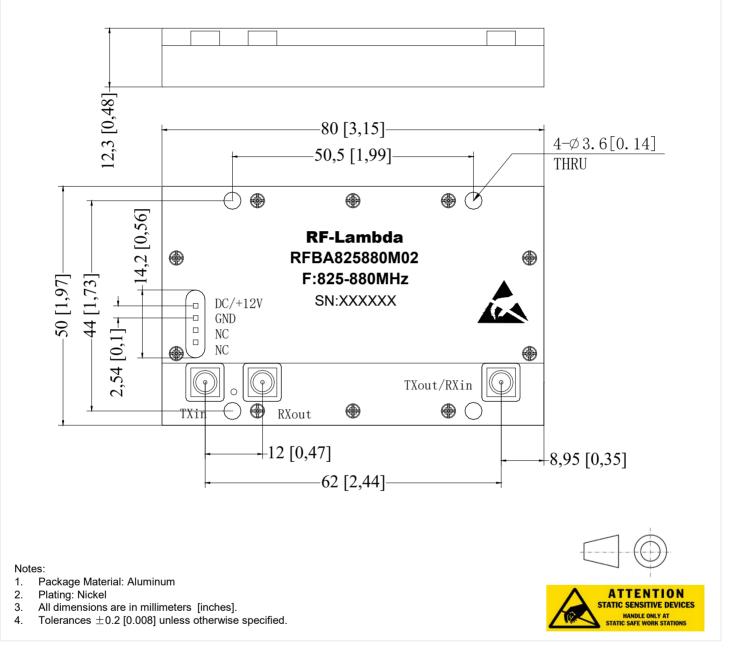
ACPR(@±5MHz Bandwidth)



RFBA825880M02



Outline Drawing



Additional Information

Documentation	Webpage	
ESD Policy	https://rflambda.com/pdf/rflambda_esd_control.pdf	
Connector Torque Specifications	https://www.rflambda.com/pdf/Torque_Specifications.pdf	
Random Vibration Test Standard	https://www.rflambda.com/pdf/rflambda_random_vibration_MIL-STD-202G.pdf	



Ordering Information

Part Number	Modification	Description
RFBA825880M02	Input /Output connector MCX-KE	825MHz-880MHz Bi-Directional Power Amplifier

Amplifier Use

Ensure that the amplifier input and output ports are safely terminated into a proper 50 ohm load before turning on the power. Never operate the amplifier without a load. A proper 50 ohm load is defined as a load with impedance less than 1.9:1 or return loss larger than 10dB relative to 50 Ohm within the specified operating band width.

Power Supply Requirements

Power supply must be able to provide adequate current for the amplifier. Power supply should be able to provide 1.5 times the typical current or 1.2 times the maximum current (whichever is greater).

In most cases, RF - Lambda amplifiers will withstand severe mismatches without damage. However, operation with poor loads is discouraged. If prolonged operation with poor or unknown loads is expected, an external device such as an isolator or circulator should be used to protect the amplifier.

Ensure that the power is off when connecting or disconnecting the input or output of the amp.

Prevent overdriving the amplifier. Do not exceed the recommended input power level.

Adequate heat-sinking required for RF amplifier modules. Please inquire.

Amplifiers do not contain Thermal protection, Reverse DC polarity or Over voltage protection with the exception of a few models. Please inquire.

Proper electrostatic discharge (ESD) precautions are recommended to avoid performance degradation or loss of functionality.

What is not covered with warranty?

Each RF - Lambda amplifier will go through power and temperature stress testing. Since the die, ICs or MMICs are fragile, these are not covered by warranty. Any damage to these will NOT be free to repair.

Important Notice

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